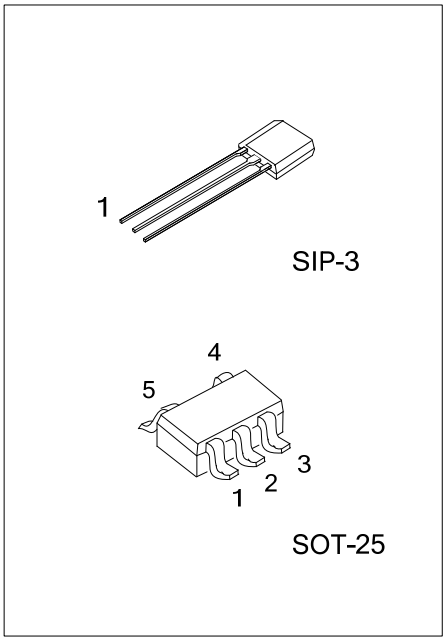
SK8552 *LINEAR INTEGRATED CIRCUIT*

LOW VOLTAGE OPERATION HALL IC



■ DESCRIPTION

SK8552 is a semiconductor integrated circuit utilizing the Hall effect. It has been so designed as to operate in the alternating magnetic field especially at low supply voltage and operation over extended temperature ranges to +125℃.This Hall IC is suitable for application to various kinds of sensors, contact-less switches, and the like.

■ FEATURES

* Wide supply voltage range of 3V to 20V
* Wide temperature operation range of -20℃~+125℃
* TTL and MOS IC are directly drivable by the output
* The life is semipermanent because it employs contactless parts
* Equipped with an output pull-up resistor (typical 20kΩ)

■ APPLICATION

* Position sensor
* Contact-less sensor
* Detection of cover (open/close)

■ ORDERING INFORMATION

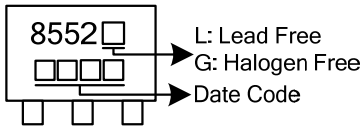
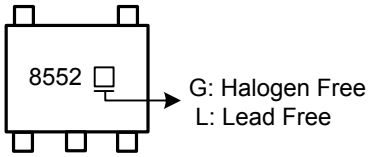
Ordering Number		Package	Pin Assignment					Packing
Lead Free	Halogen Free		1	2	3	4	5	
SK8552L-AF5-R	SK8552G-AF5-R	SOT-25	G	G	O	I	N	Tape Reel
SK8552L-G03-B	SK8552G-G03-B	SIP-3	I	G	O	-	-	Tape Box
SK8552L-G03-K	SK8552G-G03-K	SIP-3	I	G	O	-	-	Bulk

Note: Pin Assignment: I: V_{CC} O:V_{OUT} G:GND N: No Connection

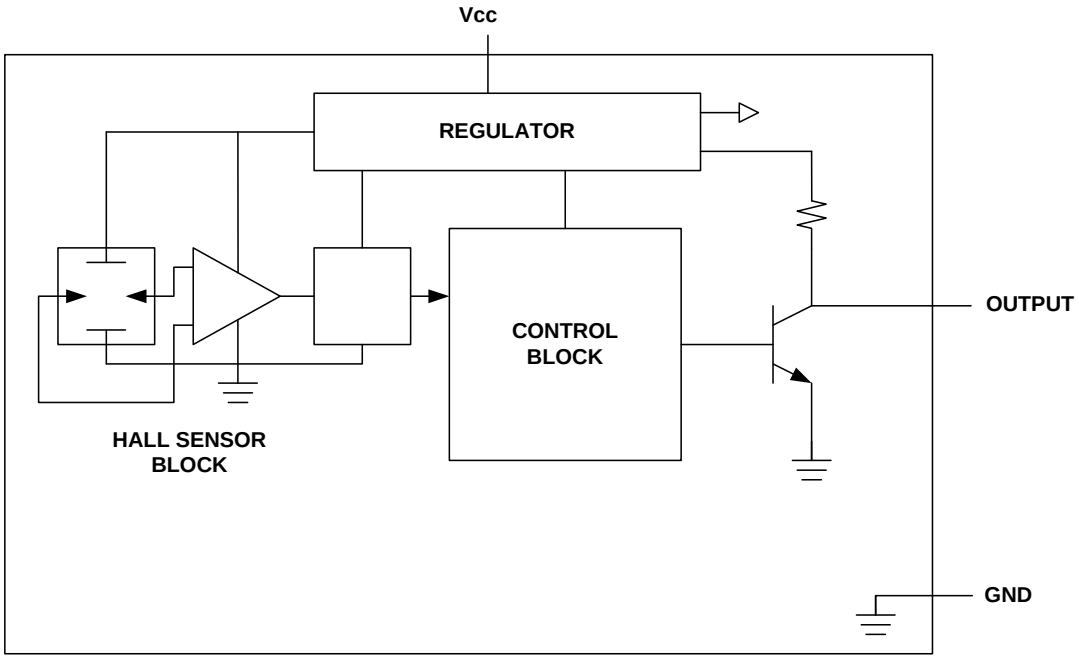
SK8552L-AF5-R

(1)Packing Type	(1) B: Tape Box, K: Bulk, R: Tape Reel
(2)Package Type	(2) AF5: SOT-25, G03: SIP-3
(3)Lead Free	(3) G: Halogen Free, L: Lead Free

■ MARKING

SIP-3	SOT-25
	

■ BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATINGS (T_A = 25℃)

PARAMETER		SYMBOL	RATINGS	UNIT
Supply Voltage		V_{CC}	3~20	V
Supply Current		I_{CC}	10	mA
Output Current		I_{OUT}	10	mA
Power Dissipation	SIP-3	P_D	400	mW
	SOT-25		200	mW
Junction Temperature		T_J	+125	°C
Operating Temperature		T_{OPR}	-20~ +125	°C
Storage Temperature		T_{STG}	-55~+150	°C

Note 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (T_A = 25℃)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Output voltage SH	V_{OHS}	V_{CC} =3V,I_{OUT} =-10μA,B=100G		2.8	3	V
Output voltage NH	V_{OHN}	V_{CC} =3V,I_{OUT} =-10μA,B=-100G		2.8	3	V
Output voltage SL	V_{OLS}	V_{CC} =3V, I_{OUT} =1mA,B=5G			0.7	V
Output voltage NL	V_{OLN}	V_{CC} =3V, I_{OUT} =1mA,B=-5G			0.7	V
Output current 1	I_{OHS}	V_{CC} =3V,V_{OUT} =3V , B=100G		10		mA
Output current 2	I_{OHN}	V_{CC} =3V,V_{OUT} =3V , B=-100G		10		mA
Supply current	I_{CC}	V_{CC} =3V, B=5G		5		mA
Output switching time	T_R			5		μS
	T_F			1		μS
MAGNETIC CHARACTERISTICS (over operating supply voltage range)						
Operating magnetic flux density	BHLS	V_{CC} =3V	20			G
Operating magnetic flux density	BHLN	V_{CC} =3V	-20			G
Operating magnetic flux density	BLHS	V_{CC} =3V			100	G
Operating magnetic flux density	BLHN	V_{CC} =3V			-100	G

■ PACKAGE INFORMATION

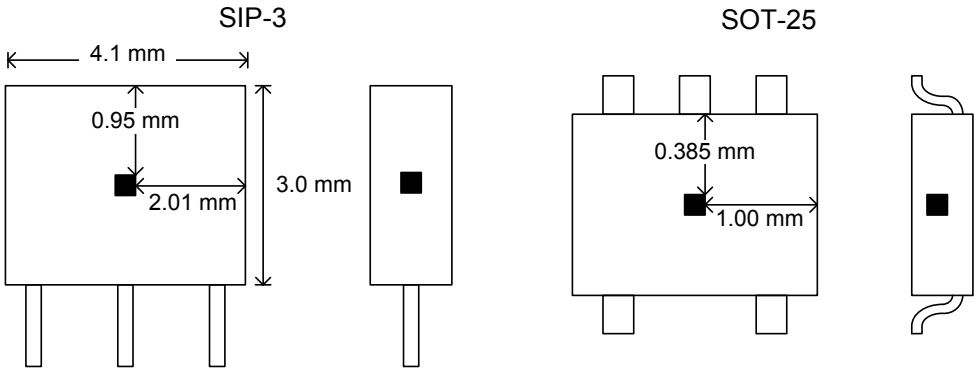


Fig. 1 SENSOR LOCATIONS

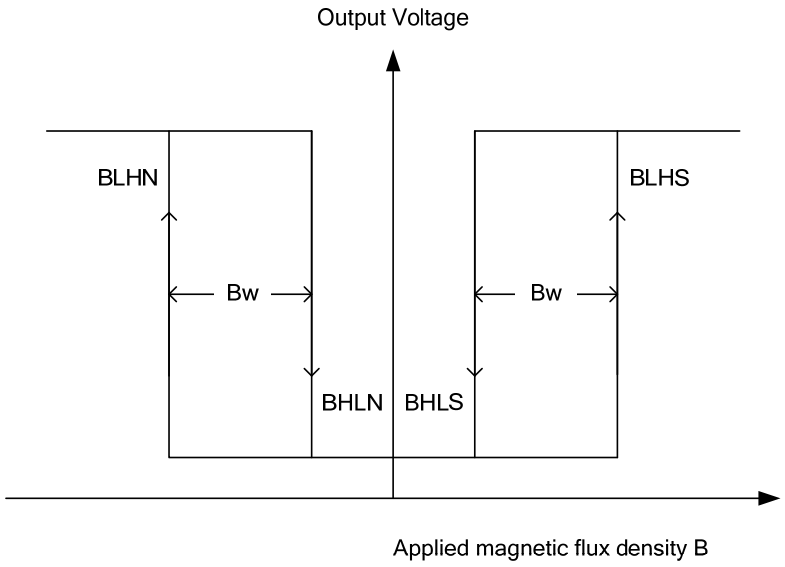


Fig. 2 OPERATING MAGNETIC FLUX DENSITY

■ TYPICAL APPLICATION CIRCUIT